# **OSRAM** SU CULFP1.VC Datasheet

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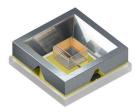




## OSLON® UV 3535

## SU CULFP1.VC

This compact UV-C LED is part of the OSLON UV series. It allows a flexible design for any application which requires UV-C radiation.





## **Applications**

- Agriculture & Horticulture

- UV-C Disinfection & Treatment

### **Features**

- Package: Ceramic package
- Chip technology: UV Flip chip
- Color: λ<sub>peak</sub> = 265 nm (• ultraviolet (UV-C))
- ESD: 5 kV acc. to ANSI/ESDA/JEDEC JS-001 (HBM)
- Typ. Radiation: 120° (0°), 120° (90°)
- Radiant Flux: typ. 115 mW
- Radiant Efficiency: typ. 5.3 %



## **Ordering Information**

Туре	Total radiant flux <sup>1)</sup> I <sub>F</sub> = 350 mA Φ <sub>E</sub>	Ordering Code	
SU CULFP1.VC-CBCF-45-1	90 140 mW	Q65113A4412	

## **UV-C RISK GROUP 3**



**WARNING UV-C** emitted from this product. Avoid eye and skin exposure to unshielded product. Follow installation instructions and user manual.



## **Maximum Ratings**

Parameter	Symbol		Values
Operating Temperature	T <sub>op</sub>	min.	-40 °C
	σp	max.	85 °C
Storage Temperature	T <sub>stg</sub>	min.	-40 °C
	Stg	max.	100 °C
Junction Temperature	T <sub>j</sub>	max.	100 °C
Forward current	I <sub>F</sub>	min.	100 mA
T <sub>s</sub> = 25 °C	·	max.	500 mA
Surge Current t ≤ 0.1 ms; D = 10 %; T <sub>s</sub> = 25 °C	I <sub>FS</sub>	max.	700 mA
ESD withstand voltage acc. to ANSI/ESDA/JEDEC JS-001 (HBM)	V <sub>ESD</sub>		5 kV
Reverse voltage 2)	V <sub>R</sub>		Not designed for reverse operation



## Characteristics

 $I_{_{\rm F}}$  = 350 mA;  $T_{_{
m S}}$  = 25 °C

Parameter	Symbol		Values
Peak Wavelength <sup>3)</sup>	$\lambda_{peak}$	min. typ.	260 nm 265 nm 270 nm
Forward Voltage <sup>4)</sup> I <sub>F</sub> = 350 mA	V <sub>F</sub>	max. min. typ. max.	5.5 V 6.2 V 6.5 V
Reverse current <sup>2)</sup>	I <sub>R</sub>		Not designed for reverse operation
Real thermal resistance junction/solderpoint <sup>5)</sup>	$R_{thJS real}$	typ.	5.6 K / W
Electrical thermal resistance junction/solderpoint with efficiency $\eta_{\rm e}$ = 4.87 %	$R_{thJS elec.}$	typ.	5.3 K / W



## **Brightness Groups**

Group	Total radiant flux <sup>1)</sup> I <sub>F</sub> = 350 mA min. Φ <sub>E</sub>	Total radiant flux <sup>1)</sup> I <sub>F</sub> = 350 mA max. Φ <sub>E</sub>	
СВ	90 mW	100 mW	
CC	100 mW	110 mW	
CD	110 mW	120 mW	
CE	120 mW	130 mW	
CF	130 mW	140 mW	

## Forward Voltage Groups

Group Forward Voltage <sup>4)</sup> I <sub>F</sub> = 350 mA min.		Forward Voltage <sup>4)</sup> I <sub>F</sub> = 350 mA max.	
V3	V <sub>F</sub> 5.5 V	0.0 V	
V4	6.0 V	6.5 V	

## Wavelength Groups

Group	Peak Wavelength 3)	Peak Wavelength 3)
	min.	max.
	$\lambda_{peak}$	λ <sub>peak</sub>
4	260 nm	265 nm
5	265 nm	270 nm



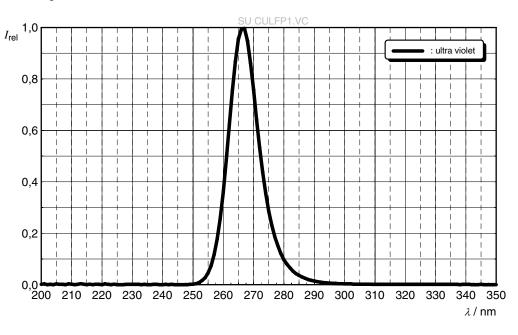
## Group Name on Label

Example: CB-4-V3 Brightness	Wavelength	Forward Voltage
СВ	4	V3



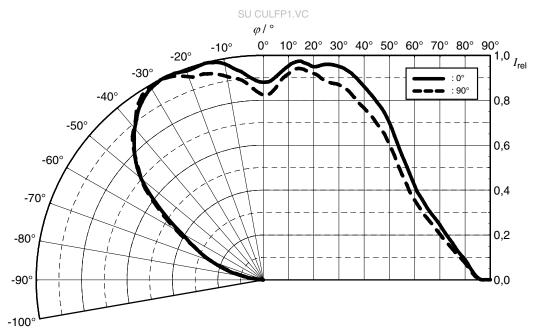
## **Relative Spectral Emission**<sup>6)</sup>

 $I_{rel}$  = f ( $\lambda$ );  $I_{F}$  = 350 mA;  $T_{S}$  = 25 °C



### **Radiation Characteristics**<sup>6)</sup>

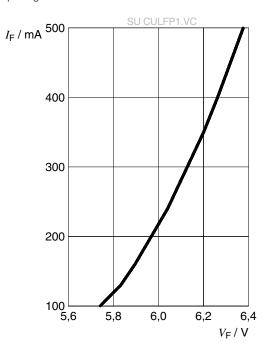
 $I_{rel} = f(\phi); T_{s} = 25 \text{ °C}$ 





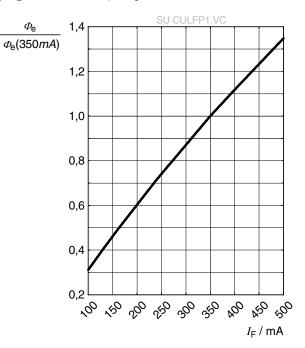
#### Forward current <sup>6)</sup>

 $I_F = f(V_F); T_S = 25 \text{ °C}$ 

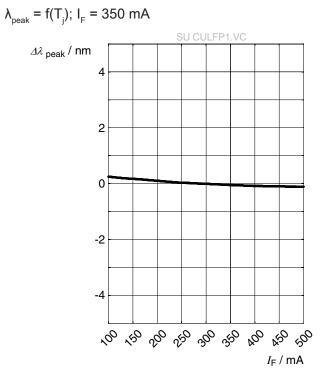


## Relative Radiant Power <sup>6), 7)</sup>

 $\Phi_{\rm E}/\Phi_{\rm E}(350 \text{ mA}) = f(I_{\rm E}); T_{\rm S} = 25 \text{ °C}$ 



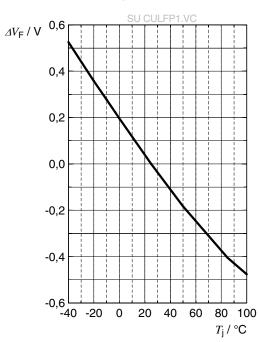
## Peak Wavelength <sup>6)</sup>





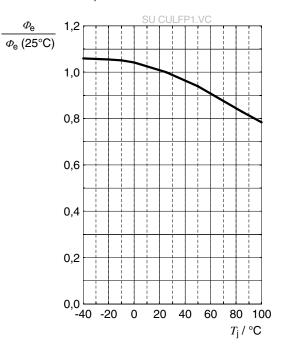
## Forward Voltage <sup>6)</sup>

 $\Delta V_{_F} = V_{_F} - V_{_F}(25 \text{ °C}) = f(T_{_J}); I_{_F} = 350 \text{ mA}$ 



## **Relative Radiant Power**<sup>6)</sup>

 $\Phi_{_{\rm E}}/\Phi_{_{\rm E}}(25 \ ^{\circ}{\rm C}) = f(T_{_{\rm i}}); I_{_{\rm F}} = 350 \text{ mA}$ 

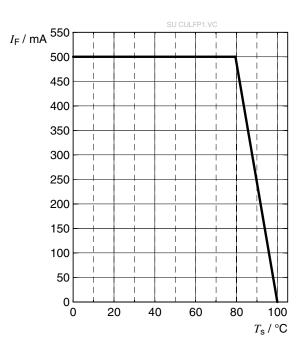


## Peak Wavelength <sup>6)</sup>



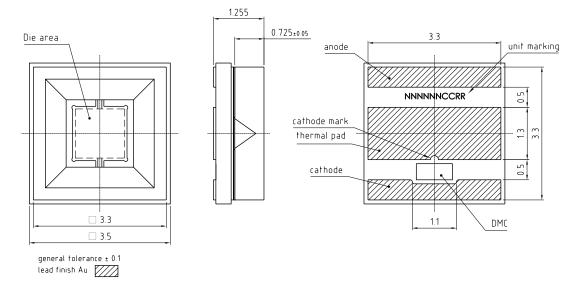
## Max. Permissible Forward Current <sup>5)</sup>

 $I_F = f(T)$ 





## Dimensional Drawing <sup>8)</sup>



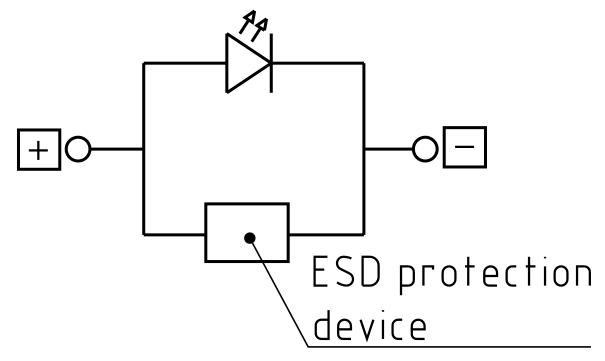
C67062-A0461-A1-04

## **Further Information:**

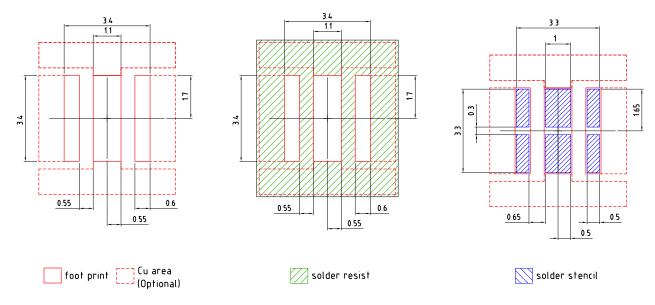
Approximate Weight:	36.0 mg
Package marking:	Cathode
ESD advice:	LED is protected by ESD device which is connected in parallel to LED-Chip.



#### **Electrical Internal Circuit**



#### **Recommended Solder Pad**<sup>8)</sup>



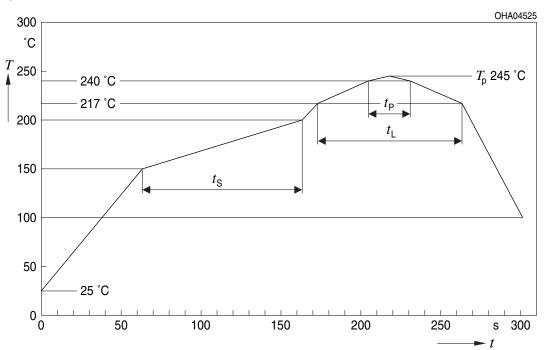
#### E067.0346.22-01

For superior solder joint connectivity results we recommend soldering under standard nitrogen atmosphere. Further information can be found in our Application Note: "Handling and Processing Details for Ceramic LEDs". Package not suitable for any kind of wet cleaning or ultrasonic cleaning.



## **Reflow Soldering Profile**





Profile Feature	Symbol	Pb	Pb-Free (SnAgCu) Assembly		
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat <sup>•</sup> ) 25 °C to 150 °C			2	3	K/s
Time t <sub>s</sub> T <sub>Smin</sub> to T <sub>Smax</sub>	t <sub>s</sub>	60	100	120	S
Ramp-up rate to peak <sup>*)</sup> $T_{smax}$ to $T_{P}$			2	3	K/s
Liquidus temperature	TL		217		°C
Time above liquidus temperature	t		80	100	S
Peak temperature	Τ <sub>Ρ</sub>		245	260	°C
Time within 5 °C of the specified peak temperature $T_{p}$ - 5 K	t <sub>P</sub>	10	20	30	S
Ramp-down rate* T <sub>P</sub> to 100 °C			3	6	K/s
Time 25 °C to T <sub>P</sub>				480	S

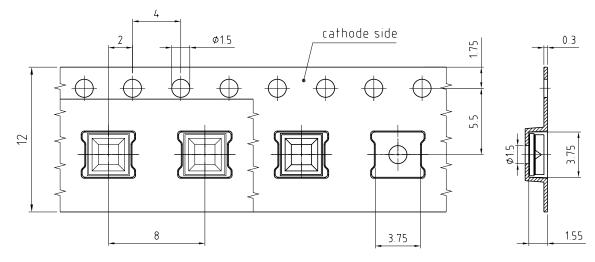
All temperatures refer to the center of the package, measured on the top of the component

 $^{\ast}$  slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range

#### SU CULFP1.VC DATASHEET



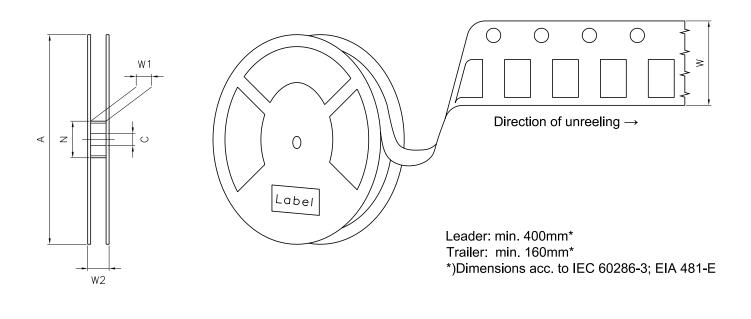
## Taping<sup>8)</sup>



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## Tape and Reel <sup>9)</sup>

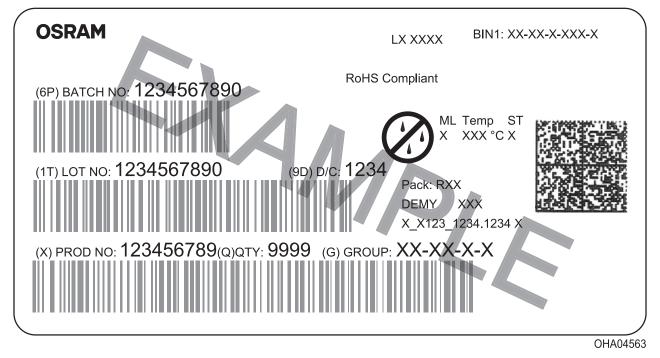


## **Reel Dimensions**

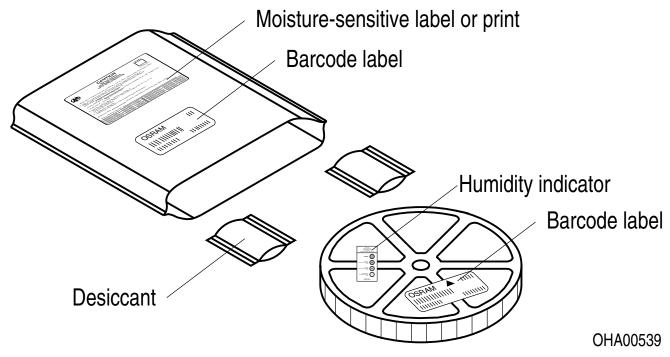
А	W	N <sub>min</sub>	W <sub>1</sub>	$W_{2 \max}$	Pieces per PU
180 mm	12 + 0.3 / - 0.1 mm	60 mm	12.4 + 2 mm	18.4 mm	500



## Barcode-Product-Label (BPL)



## Dry Packing Process and Materials<sup>8)</sup>



Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card according JEDEC-STD-033.



## Notes

The evaluation of eye safety occurs according to the standard IEC 62471:2006 (photo biological safety of lamps and lamp systems). Within the risk grouping system of this IEC standard, the device specified in this data sheet falls into **high risk group – RG 3**. WARNING - UV emitted from this product. Avoid eye and skin contact to unshielded product.

Subcomponents of this device contain, in addition to other substances, metal filled materials including silver. Metal filled materials can be affected by environments that contain traces of aggressive substances. Therefore, we recommend that customers minimize device exposure to aggressive substances during storage, production, and use. Devices that showed visible discoloration when tested using the described tests above did show no performance deviations within failure limits during the stated test duration. Respective failure limits are described in the IEC60810.

Changes to the content of this datasheet may occur without further notification. JEDEC 46C constitutes the guideline of the change management for the device specified in this document.

Based on very short life cycle times in chip technology this component is subject to frequent adaption to the latest chip technology.

For further application related information please visit https://ams-osram.com/support/application-notes



## Disclaimer

#### Attention please!

The information describes the type of component and shall not be considered as assured characteristics. Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

If printed or downloaded, please find the latest version on our website.

#### Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office. By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

#### Product and functional safety devices/applications or medical devices/applications

Our components are not developed, constructed or tested for the application as safety relevant component or for the application in medical devices.

Our products are not qualified at module and system level for such application.

An entire (100%) testing shall be performed after assembly of our product to the final product. Our products are not qualified at module and system level for such application. Customer is fully responsible and accountable for detection capability in case of sudden changes in electro-optical characteristics at component level.

In case buyer – or customer supplied by buyer – considers using our components in product safety devices/ applications or medical devices/applications, buyer and/or customer has to inform our local sales partner immediately and we and buyer and/or customer will analyze and coordinate the customer-specific request between us and buyer and/or customer.

Please carefully read the below instructions.

WARNING: Each user bears full responsibility for making their own determination as to the suitability of our products, recommendations or advice for its own end use. Each user must identify and perform all tests and analyses necessary to ensure that its finished application incorporating our products will be safe and suitable for use under end-use conditions. We make no warranty or guarantee, express or implied, as to results obtained in end-use, nor of any design incorporating its products, recommendations or advice.

WARNING: High intensity ultraviolet-C (UV-C) radiation is emitted from this product, which is harmful to skin and eyes. Take appropriate protective measures to avoid any exposure to direct or reflected UV-C radiation.

WARNING: During operating lifetime of our UV-C product different aging mechanisms can cause failures. This may lead to a significant deviation of the function in the final product and application. Please contact us in advance for further information.



## Glossary

- <sup>1)</sup> **Brightness:** Brightness groups are tested at a current pulse duration of 10 ms and a tolerance of  $\pm 10$  %.
- <sup>2)</sup> **Reverse Operation:** Not designed for reverse operation. Continuous reverse operation can cause migration and damage of the device.
- <sup>3)</sup> **Peak Wavelength:** Wavelengths are tested at a current pulse duration of 10 ms and a tolerance of ±3 nm.
- <sup>4)</sup> **Forward Voltage:** Forward voltages are tested at a current pulse duration of 1 ms and a tolerance of ±0.1 V.
- <sup>5)</sup> **Thermal Resistance:** Rth max is based on statistic values ( $6\sigma$ ) used for Derating.
- <sup>6)</sup> **Typical Values:** Due to the special conditions of the manufacturing processes of semiconductor devices, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.
- <sup>7)</sup> **Characteristic curve:** In the range where the line of the graph is broken, you must expect higher differences between single devices within one packing unit.
- <sup>8)</sup> **Tolerance of Measure:** Unless otherwise noted in drawing, tolerances are specified with ±0.1 and dimensions are specified in mm.
- <sup>9)</sup> **Tape and Reel:** All dimensions and tolerances are specified acc. IEC 60286-3 and specified in mm.



## **Revision History**

Version	Date	Change
1.0	2024-10-07	Initial Version
1.1	2024-10-22	Reflow Soldering Profile



EU RoHS and China RoHS compliant product 此产品符合欧盟 RoHS 指令的要求; 按照中国的相关法规和标准, 不含有毒有害物质或元素。

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